



ELECTRONICS, INC.  
 44 FARRAND STREET  
 BLOOMFIELD, NJ 07003  
 (973) 748-5089  
<http://www.nteinc.com>

## NTE80C95, NTE80C96, NTE80C97 Integrated Circuit TTL, CMOS, TRI-STATE Hex Buffers

### Description:

These gates are monolithic complementary MOS (CMOS) integrated circuits in a 16-Lead DIP type package constructed with N- and P-channel enhancement mode transistors. These devices convert CMOS or TTL outputs to TRI-STATE outputs with no logic inversion, the NTE80C96 and the NTE80C98 provide the logical opposite of the input signal. The NTE80C95 and the NTE80C96 have common TRI-STATE controls for all six devices. The NTE80C97 and the NTE80C98 have two TRI-STATE controls; one for two devices and one for the other four devices. Inputs are protected from damage due to static discharge by diode clamps to  $V_{CC}$  and GND.

### Features:

- Wide Supply Voltage Range: 3.0V to 15V
- Guaranteed Noise Margin: 1.0V
- High Noise Immunity: 0.45  $V_{CC}$  (typ)
- TTL Compatible: Drive 1 TTL Load
- Typical Propagation Delay: 40ns into 150pF Load

### Applications:

- Bus Drivers

### Absolute Maximum Ratings: (Note 2)

Voltage at any Pin	.....	-0.3V to $V_{CC} + 0.3V$
Operating Temperature Range	.....	-40° to +85°C
Storage Temperature Range	.....	-65°C to +150°C
Package Dissipation	.....	500mW
Power Supply Voltage ( $V_{CC}$ )	.....	18V
Lead Temperature (During Soldering, 10sec Max)	.....	+300°C

Note 1. **NTE80C95** is a **discontinued** device and **no longer available**.

Note 2. "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

### DC Electrical Characteristics: (Note 3)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit	
<b>CMOS to CMOS</b>							
Logical "1" Input Voltage	$V_{IN(1)}$	$V_{CC} = 5V$	3.5	-	-	V	
		$V_{CC} = 10V$	8.0	-	-	V	
Logical "0" Input Voltage	$V_{IN(0)}$	$V_{CC} = 5V$	-	-	1.5	V	
		$V_{CC} = 10V$	-	-	2.0	V	
Logical "1" Output Voltage	$V_{OUT(1)}$	$V_{CC} = 5V$	4.5	-	-	V	
		$V_{CC} = 10V$	9.0	-	-	V	
Logical "0" Output Voltage	$V_{OUT(0)}$	$V_{CC} = 5V$	-	-	0.5	V	
		$V_{CC} = 10V$	-	-	1.0	V	
Logical "1" Input Current	$I_{IN(1)}$	$V_{CC} = 15V$	-	0.005	1.0	$\mu A$	
Logical "0" Input Current	$I_{IN(0)}$		-1.0	-0.005	-	$\mu A$	
Output Current in High Impedance State	$I_{OZ}$	$V_{CC} = 15V$	$V_O = 15V$	-	0.005	1.0	$\mu A$
			$V_O = 0V$	-1.0	-0.005	-	$\mu A$
Supply Current	$I_{CC}$	$V_{CC} = 15V$	-	0.01	15	$\mu A$	
<b>TTL Interface</b>							
Logical "1" Input Voltage	$V_{IN(1)}$	$V_{CC} = 4.75V$	$V_{CC}-1.5$	-	-	V	
Logical "0" Input Voltage	$V_{IN(0)}$	$V_{CC} = 4.75V$	-	-	0.8	V	
Logical "1" Output Voltage	$V_{OUT(1)}$	$V_{CC} = 4.75V, I_O = -1.6mA$	2.4	-	-	V	
Logical "0" Output Voltage	$V_{OUT(0)}$	$V_{CC} = 4.75V, I_O = -1.6mA$	-	-	0.4	V	
<b>Output Drive (Short-Circuit Current)</b>							
Output Source Current	$I_{SOURCE}$	$V_{CC} = 5V, V_{IN(1)} = 5V$	$T_A = +25^\circ C, V_{OUT} = 0V$	-4.35	-	-	mA
		$V_{CC} = 10V, V_{IN(1)} = 10V$		-20	-	-	mA
Output Sink Current	$I_{SINK}$	$V_{CC} = 5V, V_{IN(0)} = 5V$	$T_A = +25^\circ C, V_{OUT} = V_{CC}$	4.35	-	-	mA
		$V_{CC} = 10V, V_{IN(0)} = 10V$		20	-	-	mA

Note 3. Max/Min Limits apply across temperature range, unless otherwise noted.

### AC Electrical Characteristics: ( $T_A = +25^\circ C, C_L = 50pF$ , Note 4 unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit	
Propagation Delay Time to a Logical "0" or Logical "1" from Data Input to Output NTE80C95, NTE80C97	$t_{pd0}, t_{pd1}$	$V_{CC} = 5V$	-	60	100	ns	
			$V_{CC} = 10V$	-	25	40	ns
		$V_{CC} = 5V$	-	70	150	ns	
			$V_{CC} = 10V$	-	35	75	ns
Propagation Delay Time to a Logical "0" or Logical "1" from Data Input to Output NTE80C95, NTE80C97	$t_{pd0}, t_{pd1}$	$C_L = 150pF$	$V_{CC} = 5V$	-	85	160	ns
				$V_{CC} = 10V$	-	40	80
			$V_{CC} = 5V$	-	95	210	ns
				$V_{CC} = 10V$	-	45	110

Note 4. AC parameters are guaranteed by DC correlated testing.

**AC Electrical Characteristics (Cont'd):** ( $T_A = +25^\circ\text{C}$ ,  $C_L = 50\text{pF}$ , Note 4 unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit	
Delay from Disable Input to High Impedance State (from Logical "1" or Logical "0") NTE80C95	$t_{1H}$ , $t_{0H}$	$R_L = 10\text{k}$ , $C_L = 5\text{pF}$	$V_{CC} = 5\text{V}$	-	80	135	ns
			$V_{CC} = 10$	-	50	90	ns
NTE80C96			$V_{CC} = 5\text{V}$	-	100	180	ns
NTE80C97			$V_{CC} = 10\text{V}$	-	70	125	ns
			$V_{CC} = 5\text{V}$	-	70	125	ns
			$V_{CC} = 10\text{V}$	-	50	90	ns
Delay from Disable Input to Logical "1" (from High Impedance State) NTE80C95	$t_{H1}$ , $t_{H0}$	$R_L = 10\text{k}$ , $C_L = 5\text{pF}$	$V_{CC} = 5\text{V}$	-	120	200	ns
			$V_{CC} = 10$	-	50	90	ns
NTE80C96			$V_{CC} = 5\text{V}$	-	130	225	ns
NTE80C97			$V_{CC} = 10\text{V}$	-	60	110	ns
			$V_{CC} = 5\text{V}$	-	95	175	ns
			$V_{CC} = 10\text{V}$	-	40	80	ns
Input Capacitance	$C_{IN}$	Any Input, Note 5	-	5	-	pF	
Output Capacitance TRI-STATE	$C_{OUT}$	Any Output, Note 5	-	11	-	pF	
Power Dissipation Capacitance	$C_{PD}$	Note 6	-	60	-	pF	

Note 4. AC parameters are guaranteed by DC correlated testing.

Note 5. Capacitance is guaranteed by periodic testing.

Note 6.  $C_{PD}$  determines the no load AC power consumption of any CMOS device.

**Truth Table (NTE80C95, NTE80C96):**

Disable $DIS_1$	Input $DIS_2$	Input	Output
0	0	0	0
0	0	1	1
0	1	X	H-z
1	0	X	H-z
1	1	X	H-z

**Truth Table (NTE80C97):**

Disable $DIS_4$	Input $DIS_2$	Input	Output
0	0	0	0
0	0	1	1
X	1	X	H-z *
1	X	X	H-z **

\* Output 5-6 Only

\*\* Output 1-4 Only

X = Don't Care

### Pin Connection Diagram

